PHILOSOPHICAL MAGAZINE LETTERS

CONTENTS OF VOL. 61

NUMBER 1—JANUARY PAGE

Diffusion equation for crack growth in solids
By V. S. KRIVOBODROV 1

Mechanism of boron-induced ductility in polycrystalline Ni_3Al
By T. K. CHAKI 5

New icosahed: al alloys with superlattice order in the Al–Pd–Mn system prepared by rapid solidification
By A. P. TSAI, A. INOUE, Y. YOKOYAMA and T. MASUMOTO 9

Stable Al–Cu–Co decagonal quasicrystals with decaprismatic solidification morphology
By L. X. HE, Y. K. WU, X. M. MENG and K. H. KUO 15

Simultaneous growth of a crystalline phase and a quasicrystalline phase in lateral Al–Pd diffusion couples
By B. BLANPAIN, J. C. LIU, D. A. LILIENFELD and J. W. MAYER 21

A method for the simulation of high-resolution electron microscope images from non-periodic objects
By WANG YUAN-MING, HU TIAN-BAO, WEN HUO and ZENG XIAOBIAO. 29

Characterization of silicon-on-insulator field-effect structures by transient photoconductivity
By R. PANDYA and B. A. KHAN 37

NUMBER 2—FEBRUARY

Cross-sectional transmission electron microscopy of electrodeposited Ni–P alloys
By K. SHIMIZU, G. E. THOMPSON, G. C. WOOD and K. KOBAYASHI 43

High-resolution electron microscope studies of irradiation-induced crystalline-to-amorphous transition in boron carbide
By H. MORI, T. SAKATA, H. FUJITA and H. INUI 49

High-temperature stability and faceting of the icosahedral Al–Fe–Cu phase
By M. AUDIER, P. GUYOT and Y. BRECHET 55

Transformation of the octagonal quasicrystal into the β-Mn-type crystalline structure
By N. WANG and K. H. KUO 63

The Fe–Nb decagonal phase and its structure model
By A. Q. HE, Q. B. YANG and H. Q. YE 69

The effect of long-range Coulomb potential on the electronic structure of localized states in homogeneous intrinsic amorphous semiconductors
By S. D. BARANOVSKII and M. SILVER 77

NUMBER 3—MARCH

PAGE

Cathodoluminescence-mode imaging of dislocations in zinc oxide
By J. T. Czernuszka and N. Pratt 83

Rules for combining structural units of grain boundaries
By A. P. Sutton and R. W. Balluffi 91

Antiphase domains and {011} twins in TiAl
By C. R. Feng, D. J. Michel and C. R. Crowe 95

Solid-phase epitaxy of implanted silicon at liquid nitrogen and room temperature induced by electron irradiation in the electron microscope
By F. Corticelli, G. Lulli and P. G. Merli 101

X-ray study of phason strain in Al-based quasicrystals
By K. Edagawa 107

Formation of quasicrystalline phase and its orientation relationship with the parent phase in a duplex stainless steel
By Z. W. Hu, X. L. Jiang, J. Zhu, and S. S. Hsu 115

Experimental observation of the splitting and shifting of HOLZ lines induced by a line defect in the quasicrystalline icosahedral phase of $Al_{76}Si_4Mn_{20}$
By Renhui Wang and Mingxing Dai 119

Analysis of dislocations in icosahedral Al–Cu–Fe alloy by transmission electron microscopy
By Z. Zhang, M. Wollgarten and K. Urban 125

Structural ordering in annealed anodic oxide films on aluminium
By K. Shimizu, G. E. Thompson, G. C. Wood and K. Kobayashi 133

Long-range Finnis–Sinclair potentials
By A. P. Sutton and J. Chen 139

The limited-flux model: deuterium in boron-doped crystalline silicon
By X. W. Wu and B. Y. Tong 147

On carrier densities and lifetimes in a-Si:H at low temperatures
By T. M. Searle 153

The electronic structure and diffusivity for a fully bonded model of amorphous Si at $T=0$ K
By B. J. Hickey, J. N. Burr and G. J. Morgan 161

Errata 167

NUMBER 4—APRIL

How to see the Burgers vector of a quasicrystal dislocation
By Y. Hatwalne and S. Ramaswamy 169

PAGE

Relationship between icosahedral and monoclinic phases in Al–Cu–Fe alloy
By Y. F. CHENG, M. J. HUI, X. S. CHEN and F. H. LI 173

Nanometre hole formation in MgO using electron beams
By P. S. TURNER, T. J. BULLOUGH, R. W. DEVENISH, D. M. MAHER and C. J. HUMPHREYS 181

The order–disorder transition at twin boundaries in Cu_3Au as studied by TEM
By J. G. ANTONOPOULOS, F. W. SCHAPINK and F. D. TICHELAAR 195

Anomalous temperature dependence of the yield stress of Ti_3Al by $\{11\bar{2}1\}\langle\bar{1}\bar{1}26\rangle$ slip
By Y. MINONISHI and M. H. YOO 203

Stress-corrosion cracking in $YBa_2Cu_3O_{7-x}$ ceramic superconductor
By E. ISKEVITCH and R. CHAIM 209

Electrical properties of oxide superconductors above T_c
By N. F. MOTT 217

A fluorescence EXAFS study of the structure of copper-rich precipitates in Fe–Cu and Fe–Cu–Ni alloys
By S. PIZZINI, K. J. ROBERTS, W. J. PHYTHIAN, C. A. ENGLISH and G. N. GREAVES 223

Is the positive dielectric response of small metals related to heterogeneous catalysis?
By G. NIMTZ and P. MARQUARDT 231

Multiple-trapping carrier transport due to modulated photogeneration
By W. TOMASZEWICZ 237

Calculation of the spin–lattice coupling coefficient G_{44} from two cases for Ni^{2+} ion in cubic crystals
By ZHENG WEN-CHEN 245

Publisher's note 249

On carrier densities and lifetimes in a-Si:H at low temperatures
By T. M. SEARLE 251

NUMBER 5—MAY

The geometrical configuration of kinks on screw s erdislocations in Ni_3Al deformed at room temperature
By C. BONTEMPS and P. VEYSSIÈRE 259

Direct atomic imaging of the formation of a 60° dislocation on the (111) surface of Tb_4O_7
By X. G. NING and H. Q. YE 269

PAGE

On the stability of twins during vacuum annealing of ZnSe films grown by molecular beam epitaxy
By S. B. Sant, R. W. Smith and G. C. Weatherly 273

Strain-relief spiral buckling of a-Si:H films
By Xun-Ming Deng 281

HREM study of the chemical nature of twin planes in $CuAlO_2$
By T. Epicier and C. Esnouf 285

Metal–insulator transition in InP
By D. M. Finlayson 293

On the structural nature of aluminium-based metallic glasses
By Yi He, Huan Chen, G. J. Shiflet and S. J. Poon 297

A three-dimensional model for the octagonal phase
By M. Torres, G. Pastor and I. Jiménez 305

NUMBER 6—JUNE

Evidence for competing growth phases in ion-beam-deposited epitaxial silicon films
By K. G. Orrman-Rossiter, D. R. G. Mitchell, S. E. Donnelly, C. J. Rossouw, S. R. Glanvill, P. R. Miller, Amir H. Al-Bayati, J. A. van den Berg and D. G. Armour 311

From the decagonal phase to a related crystalline one
By M. Torres, G. Pastor and I. Jiménez 319

Analysis of TEM image contrast of quantum-dot semiconductor clusters in glasses
By Li-Chi Liu and Subhash H. Risbud 327

A novel GaAs current-controlled bipolar–unipolar transition negative differential resistance transistor prepared by molecular-beam epitaxy
By K. F. Yarn, Y. H. Wang and C. Y. Chang 333

Room-temperature operation of a novel negative differential resistance device prepared by molecular-beam epitaxy
By K. F. Yarn, Y. H. Wang and C. Y. Chang 339

Voidites in pure type IaB diamonds
By G. Van Tendeloo, W. Luyten and G. S. Woods 343

Structural disorder in AgBr: reverse Monte Carlo analysis of powder neutron-diffraction data
By D. A. Keen, R. L. McGreevy, W. Hayes and K. N. Clausen 349